



COMPLEMENTARY PAIR ENHANCEMENT MODE MOSFET

Product Summary

| Device | BV _{DSS} | R _{DS(ON)} | Ι _D T _A = +25°C |
|--------|-------------------|---------------------------------|--|
| 01 | Q1 20V | $35m\Omega @ V_{GS} = 4.5V$ | 4.5A |
| QI | | 56mΩ @ V _{GS} = 1.8V | 3.5A |
| 02 | Q2 -20V | 74mΩ @ V _{GS} = -4.5V | -3.1A |
| QZ | | 168mΩ @ V _{GS} = -1.8V | -2.0A |

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

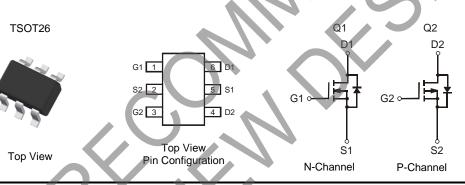
- Motor Control
- **Power Management Functions**
- **DC-DC Converters**
- Backlighting

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections Indicator: See Diagram
- Weight: 0.013 grams (Approximate)



Ordering Information (Note 5)

| Part Number | Compliance | Case | Packaging |
|---------------|------------|--------|------------------|
| DMC2038LVT-7 | Standard | TSOT26 | 3000/Tape & Reel |
| DMC2038LVTQ-7 | Automotive | TSOT26 | 3000/Tape & Reel |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and 1000ppm antimony compounds.

4. Automotive products are AEC-Q101 gualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/. 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

| | 31C | S A A A A A A A A A A A A A A A A A A A |
|------|------|---|
| | | |
| 2017 | 2018 | 2019 |
| | | |

1C = Product Type Marking Code

M = Date Code Marking = Year (ex: F = 2018)

I = Month (ex: 9 = September)

| Date Code Key | | | | | | | | | | | | |
|---------------|-----|-----|------|-----|------|-----|-----|------|-----|------|-----|------|
| Year | 201 | 7 | 2018 | | 2019 | 20 | 20 | 2021 | | 2022 | 2 | 2023 |
| Code | E | | F | | G | I | -1 | | | J | | К |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | Ν | D |



DMC2038LVT

Maximum Ratings N-CHANNEL – Q1 (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit | |
|---|-----------------|---|------------------|------------|---|
| Drain-Source Voltage | | V _{DSS} | 20 | V | |
| Gate-Source Voltage | | | V _{GSS} | ±12 | V |
| | | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | ID | 3.7 3.0 | А |
| Continuous Drain Current (Note 6) $V_{GS} = 4.5V$ | t<10s | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | Ι _D | 4.1 3.2 | А |
| | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | ID | 4.5 3.6 | А |
| Continuous Drain Current (Note 7) $V_{GS} = 4.5V$ | t<10s | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | Ι _D | 5.2 4.2 | А |
| Maximum Continuous Body Diode Forward Curre | nt (Note 7) | Is | 1.5 | А | |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1 | %) | I _{DM} | 25 | А | |

Maximum Ratings P-CHANNEL – Q2 (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit | |
|--|------------|--|------------------|--------------|---|
| Drain-Source Voltage | | | V _{DSS} | -20 | V |
| Gate-Source Voltage | | | V _{GSS} | ±12 | V |
| | | T _A = +25°C T _A = +70°C | ۱ _D | -2.6 -2.1 | A |
| Continuous Drain Current (Note 6) $V_{GS} = -4.5V$ | t<10s | T _A = +25°C T _A = +70°C | lo | -2.9 -2.4 | А |
| | | T _A = +25°C T _A = +70°C | ID | -3.1 -2.5 | А |
| Continuous Drain Current (Note 7) V_{GS} = -4.5V | t<10s | T _A = +25°C T _A = +70°C | lp | -3.8 -3.0 | А |
| Maximum Continuous Body Diode Forward Curren | t (Note 7) | I _S | -1.5 | А | |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 19 | (6) | | Ідм | -17 | А |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Units | |
|--|----------------------|----------------------------------|-------------|------|
| Total Dawar Discingtion (Note C) | $T_A = +25^{\circ}C$ | P | 0.8 | W |
| Total Power Dissipation (Note 6) | $T_A = +70^{\circ}C$ | PD | 0.5 | vv |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | P | 168 | °C/W |
| memai resistance, suriction to Ambient (note 0) | t<10s | $R_{	heta}$ JA | 120 | 0/10 |
| Total Power Dissipation (Note 7) | $T_A = +25^{\circ}C$ | D- | 1.1 | W |
| Total Fower Dissipation (Note 7) | $T_A = +70^{\circ}C$ | PD | 0.7 | vv |
| Thermal Registeres, Junction to Ambient (Note 7) | Steady State | Р | 114 | |
| Thermal Resistance, Junction to Ambient (Note 7) | t<10s | $R_{\theta JA}$ | 72 | °C/W |
| Thermal Resistance, Junction to Case (Note 7) | $R_{\theta JC}$ | 39 | | |
| Operating and Storage Temperature Range | | T _{J,} T _{STG} | -55 to +150 | °C |

Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.



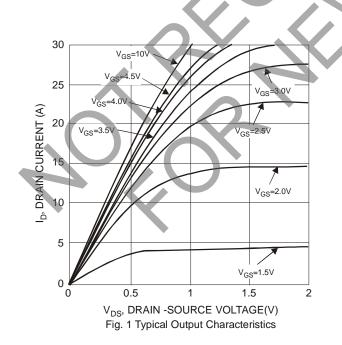
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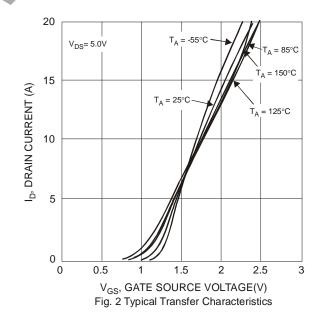
Electrical Characteristics N-CHANNEL – Q1 (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|---------------------|-----|-----|----------|------|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 20 | — | _ | V | $V_{GS} = 0V, I_D = 250 \mu A$ |
| Zero Gate Voltage Drain Current @T _C = +25°C | I _{DSS} | — | — | 1.0 | μA | $V_{DS} = 16V, V_{GS} = 0V$ |
| Gate-Source Leakage | IGSS | — | — | ±100 | nA | $V_{GS} = \pm 12V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 8) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.4 | — | 1.0 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ |
| | | | 27 | 35 | | $V_{GS} = 4.5 V, I_D = 4.0 A$ |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 33 | 43 | mΩ | $V_{GS} = 2.5 V, I_D = 2.5 A$ |
| | | - | 43 | 56 | | V _{GS} = 1.8V, I _D = 1.5A |
| Forward Transfer Admittance | Y _{fs} | - | 9 | | S | $V_{DS} = 5V, I_D = 3.4A$ |
| Diode Forward Voltage | V _{SD} | 0.4 | — | 1.1 | V | $V_{GS} = 0V, I_{S} = 1A$ |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | |
| Input Capacitance | Ciss | _ | 400 | 530 | pF | |
| Output Capacitance | Coss | _ | 70 | 90 | pF | $V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz |
| Reverse Transfer Capacitance | Crss | _ | 65 | 100 | pF | |
| Gate Resistance | Rg | - | 1.9 | - | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 5.7 | <u> </u> | nC | |
| Total Gate Charge (V _{GS} = 10V) | Qg | — | 12 | 17 | nC | |
| Gate-Source Charge | Q _{gs} | | 0.7 | -(| nC | V _{DS} = 15V, I _D = 5.8A |
| Gate-Drain Charge | Q _{gd} | | 1.4 | | nC | |
| Turn-On Delay Time | t _{D(ON)} | | 5 | 10 | ns | |
| Turn-On Rise Time | t _R | - | 8 | 16 | ns | V _{DS} = 10V, V _{GS} = 4.5V, |
| Turn-Off Delay Time | t _{D(OFF)} | | 25 | 40 | ns | $R_G = 6\Omega, I_{DS} = 1A$ |
| Turn-Off Fall Time | tF | _ | 8 | 16 | ns |] |

Notes: 8. Short duration pulse test used to minimize self-heating effect.

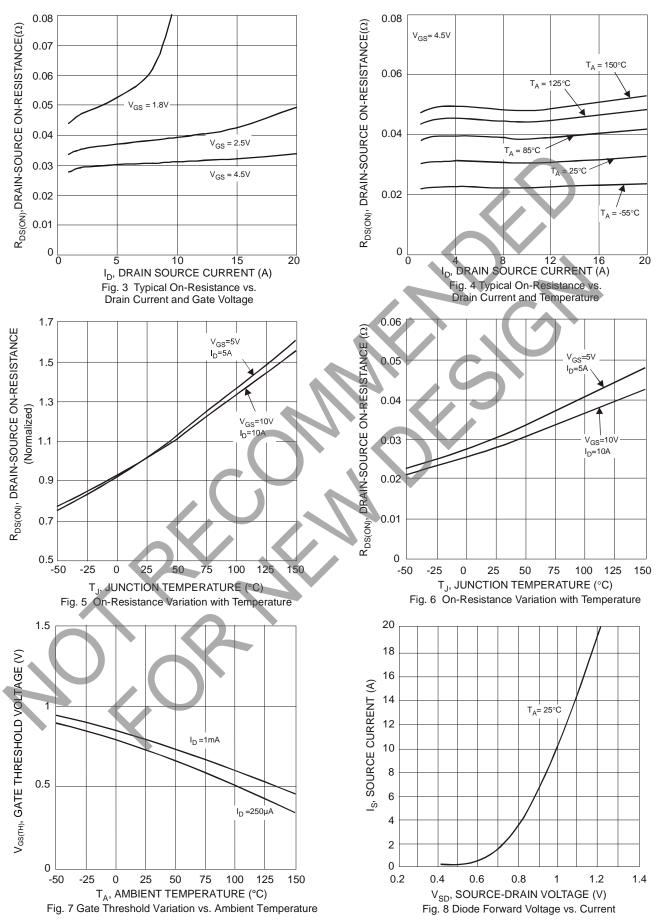
9. Guaranteed by design. Not subject to product testing.





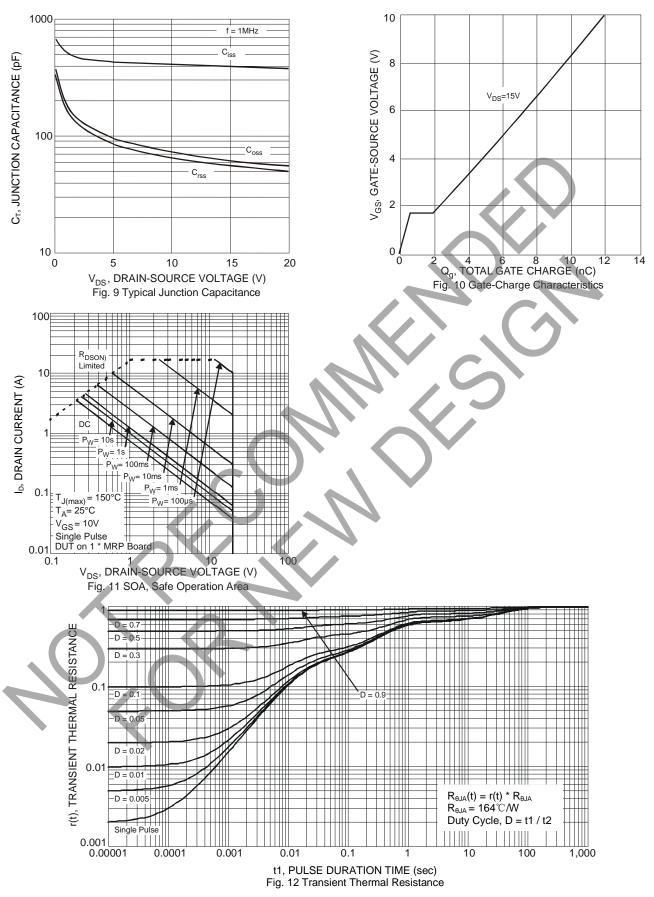


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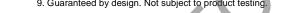


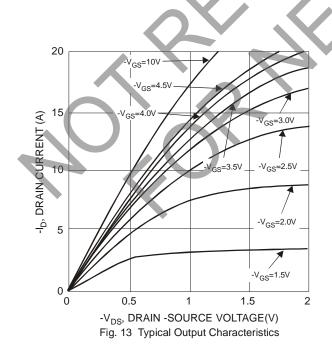


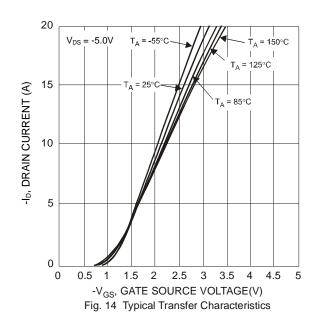
Electrical Characteristics P-CHANNEL – Q2 (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|---------------------|----------|------|------|------|---|
| OFF CHARACTERISTICS (Note 8) | 1 | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | | | V | $V_{GS} = 0V, I_D = -250\mu A$ |
| Zero Gate Voltage Drain Current @T _C = +25°C | I _{DSS} | _ | — | -1.0 | μA | $V_{DS} = -16V, V_{GS} = 0V$ |
| Gate-Source Leakage | I _{GSS} | _ | — | ±100 | nA | $V_{GS} = \pm 12V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 8) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.4 | | -1.0 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ |
| | | _ | 57 | 74 | | V _{GS} = -4.5V, I _D = -3.0A |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 76 | 110 | mΩ | V _{GS} = -2.5V, I _D = -1.5A |
| | | _ | 102 | 168 | | V _{GS} = -1.8V, I _D = -1.0A |
| Forward Transfer Admittance | Y _{fs} | _ | 10 | _ | S | V _{DS} = -5V, I _D = -3.0A |
| Diode Forward Voltage | V _{SD} | _ | -0.8 | -1.0 | V | $V_{GS} = 0V, I_{S} = -0.6A$ |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | |
| Input Capacitance | C _{iss} | _ | 530 | 705 | pF | |
| Output Capacitance | C _{oss} | _ | 70 | 95 | pF | V _{DS} = -10V, V _{GS} = 0V, f = 1.0MHz |
| Reverse Transfer Capacitance | C _{rss} | — | 60 | 90 | pF | |
| Gate Resistance | Rg | - (| 72 | | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ |
| Total Gate Charge (V _{GS} = -4.5V) | Qg | | 7 | 10 | nC | |
| Total Gate Charge (V _{GS} = -10V) | Qg | | 14 | - | nC | |
| Gate-Source Charge | Q _{gs} | | 0.95 | | nC | V _{DS} = -15V, I _D = -6A |
| Gate-Drain Charge | Q _{gd} | | 1.2 | — | nC | |
| Turn-On Delay Time | t _D (ON) | | 11 | 20 | ns | |
| Turn-On Rise Time | t _R | <u> </u> | 12 | 22 | ns | V _{DS} = -10V, V _{GS} = -4.5V, |
| Turn-Off Delay Time | t _{D(OFF)} | | 21 | 34 | ns | $R_G = 6\Omega$, $I_S = -1A$ |
| Turn-Off Fall Time | tr | - | 13 | 23 | ns | 1 |

 8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing. Notes:

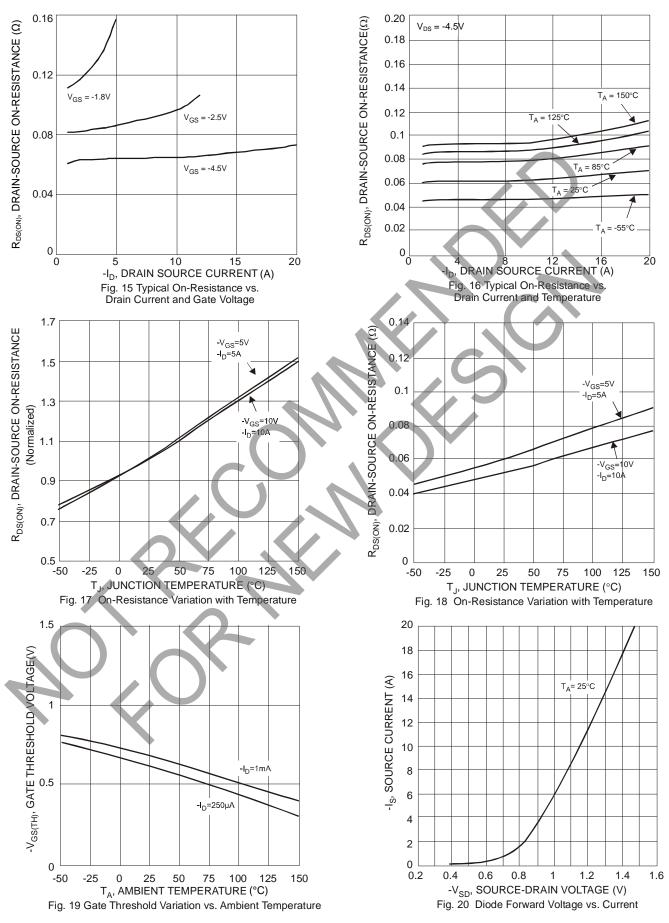








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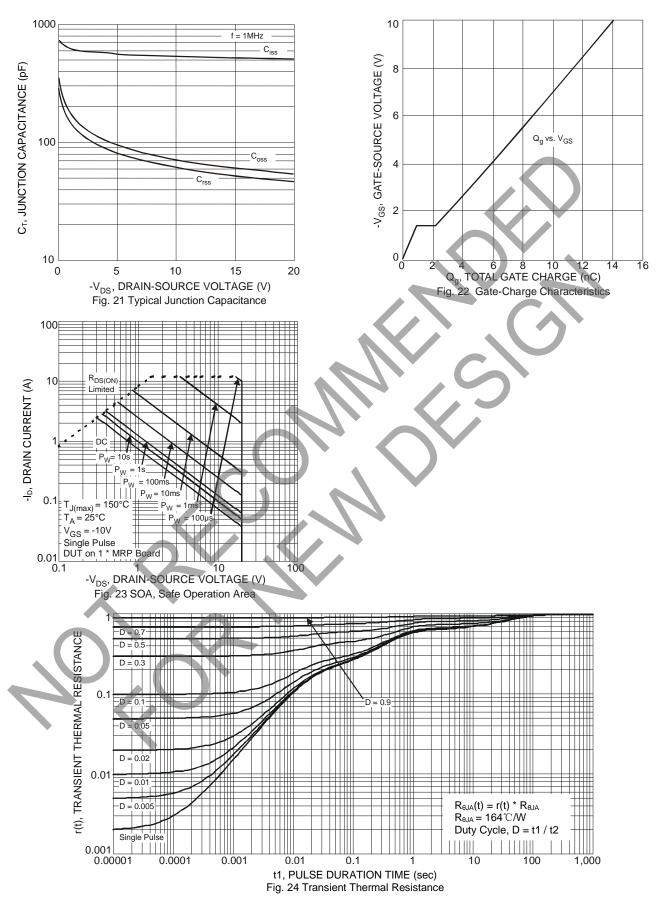


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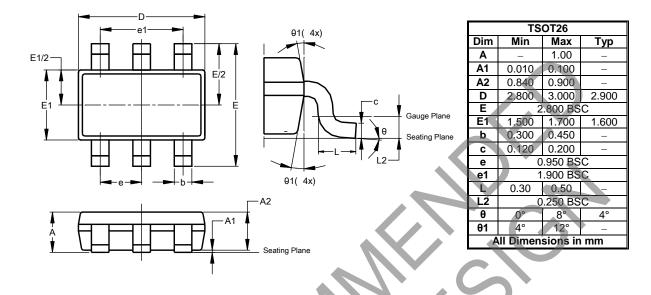




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TSOT26



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

| Dimensions | Value (in mm) |
|------------|---------------|
| С | 0.950 |
| Х | 0.700 |
| Y | 1.000 |
| Y1 | 3.199 |



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